NSN 5961-00-077-2119

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-077-2119 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Terminal Length:** 0.360 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 nonrepetitive peak reverse voltage and 600.0 forward voltage, peak **Current Rating Per Characteristic:** 2.00 amperes gate current and 60.00 amperes forward current, total rms megahertz **Power Rating Per Characteristic:** 5.0 watts gate power dissipation **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Terminal Type And Quantity:** 1 case or 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0